D OR P PACKAGE

(TOP VIEW)

TIP

V_S 2

NC

RING

3

Δ

NC – No internal connection The D package is available taped and reeled. Add R suffix (i.e., TCM1030DR).

SCTS040A - JUNE 1989 - REVISED MAY 1996

TIP

7 GND

6 GND

RING

8

5

- Meet or Exceed Bell Standard LSSGR Requirements
- Externally-Controlled Negative Firing Voltage . . . –70 V Max
- Accurately Controlled, Wide Negative Firing Voltage Range ... –5 V to –65 V
- Surge Current (see Note 1):

•	TCM1030	TCM1060
10/1000	16 A	30 A
10/160	25 A	45 A
2/10	35 A	50 A

- High Holding Current
 - TCM1030 . . . 100 mA Min
 - TCM1060 . . . 150 mA Min

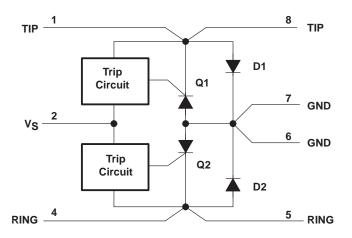
description

The TCM1030 and TCM1060 dual transient-voltage suppressors are designed specifically for telephone line-card protection against lightning and transients (voltage transients) induced by ac lines. One of the TIP terminals (pin 1 or 8) and one of the RING terminals (pin 4 or 5) are connected to the tip and ring circuits of a SLIC (subscriber-line interface circuit). The battery feed connections between the SLIC and the subscriber line are from the remaining TIP (pin 1 or 8) and RING (pin 4 or 5) through the TCM1030 or the TCM1060 to the tip and ring lines. Transients are suppressed between tip and ground, and ring and ground.

Positive transients are clamped by diodes D1 and D2. Negative transients that are more negative than V_S cause the SCRs, Q1 and Q2, to crowbar. The high holding current of the SCRs prevent dc latchup as the transient subsides.

The TCM1030 and TCM1060 are characterized for operation from -40° C to 85° C.

functional block diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NOTE 1: The notation 10/1000 refers to a waveshape having $t_r = 10 \ \mu s$ and $t_W = 1000 \ \mu s$ ending at 50% of the peak value. The notation 10/160 is $t_r = 10 \ \mu s$ and $t_W = 160 \ \mu s$. The notation 2/10 is $t_r = 2 \ \mu s$ and $t_W = 10 \ \mu s$.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



Copyright © 1996, Texas Instruments Incorporated

1

SCTS040A - JUNE 1989 - REVISED MAY 1996

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

TCM1030 nonrepetitive peak surge current (see Note 1):	10/1000 ±16 A 10/160 ±25 A 2/10 ±35 A
TCM1060 nonrepetitive peak surge current (see Note 1):	
Nonrepetitive peak surge current, t _w = 10 ms, half sinewa Continuous 60-Hz sinewave at 1 A	
Continuous total power dissipation Operating free-air temperature range, T _A Storage temperature range, T _{stg}	
Lead temperature 1,6 mm (1/16 inch) from case for 10 se	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1 The notation 10/1000 refers to a waveshape having $t_r = 10 \,\mu s$ and $t_w = 1000 \,\mu s$ ending at 50% of the peak value. The notation 10/160 is $t_r = 10 \,\mu s$ and $t_w = 160 \,\mu s$. The notation 2/10 is $t_r = 2 \,\mu s$ and $t_w = 10 \,\mu s$.

2. This value applies when the case temperature is at or below 85°C. The surge current may be repeated after the device has returned to thermal equilibrium.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	OPERATING FACTOR ABOVE T _A = 25°C	T _A = 85°C POWER RATING		
D	725 mW	5.8 mW/°C	377 mW		
Р	1000 mW	8.0 mW/°C	520 mW		



SCTS040A - JUNE 1989 - REVISED MAY 1996

PARAMETER		TEST CONDITIONS	TCM1030			TCM1060				
			MIN	TYP†	MAX	MIN	TYP†	MAX	UNIT	
Forward clamping voltage VCF (diode forward voltage) (see Note 3)		I _{FM} = 1-A transient		1.2	2		1.2	2		
	I _{FM} = 10-A transient 2.5 4			2	4	V				
	с	IFM = 16-A transient		4	5		2.5	5	ľ	
	,	IFM = 30-A transient					3.1	5		
Reverse clamping voltage V _{C(R)} (SCR on-state voltage) (see Note 3)		I _{TM} = 1-A transient		1.2	2		1.2	2		
	I _{TM} = 10-A transient		2.5	4		2.5	4	v		
		I _{TM} = 16-A transient		4	5		3	5		
	,	I _{TM} = 30-A transient					4.8	7		
I _{I(trip)}	Trip current (see Note 4)	$V_{S} = -50 V$	-100		-325	-100		-325	mA	
Ι _Η	Holding current	$V_{S} = -50 V$	-100			-150			mA	
VI(trip) Trip voltage	Tripyoltago	$V_S = -50 V$, I = trip current	-50		-55	-50		-55	v	
	The voltage	$V_S = -65 V$, I = trip current	-65		-70	-65		-70		
I _{I(stby)}	Standby current	TIP and RING at -85 V or GND, V _S = -85 V			±5			±5	μA	
	Transient overshoot voltage	$V_{S} = -50 V$, $t_{r} = 10 ns$		2.5			2.5		V	
C _{off} Off-state (high impedance) capacitance	TIP and RING at –50 V		25			25				
	capacitance	TIP and RING at GND		50			50		рF	
dv/dt	Critical rate of rise of off-state voltage (see Note 5)	V_{S} open, $V_{S} = -50 V$		-1			-1		kV/μs	

electrical characteristics over operating free-air temperature range (unless otherwise noted)

[†] All typical values are at $T_A = 25^{\circ}C$.

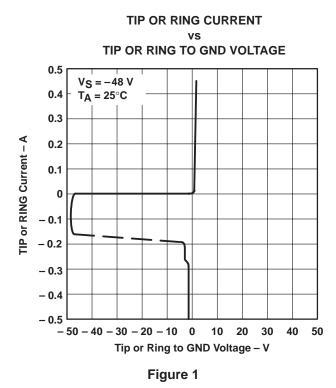
NOTES: 3. The current flows through one TIP (or RING) terminal and one of the GND terminals. The voltage is measured between the other TIP (or RING) terminal and the other GND terminal. Measurement time \leq 1 ms.

4. The negative value of trip current refers to the current flowing out of TIP or RING on the line side that is sufficient in magnitude to trigger the SCRs. Measurement time ≤ 1 ns.

5. The critical dv/dt is measured using a linear rate of rise with the maximum voltage limited to -50 V with V_S connected to TIP or RING being measured.



SCTS040A - JUNE 1989 - REVISED MAY 1996



TYPICAL CHARACTERISTICS

APPLICATION INFORMATION

The trip voltage represents the most negative level of stress applied to the system. Positive transients are clamped by diodes D1 and D2. When a negative transient is applied, current flows from V_S to TIP or RING where the transient voltage is applied. When the current through TIP or RING reaches the pulse-trip current, the SCR turns on and shorts TIP or RING to GND. The majority of the transient energy is dissipated in the external resistor (nominally 100 Ω for the TCM1030 and 50 Ω for the TCM1060). Current into V_S ceases when the SCR turns on. When the energy of the transient has been dissipated so that the current into TIP or RING due to the transient plus the battery feed supply is less than the holding current, the SCR turns off.

To help ensure reliability and consistency in the firing voltage, it is recommended that two capacitors be connected between V_S and GND, as close to the device terminals as possible. One capacitor should be a 0.1 μ F, 100 V ceramic unit and the other, a 0.47 μ F, 100 V stacked-film (not wound) metalized plastic capacitor. If inductance is present in the line to V_S, these capacitors help prevent overshoot in the firing voltage during fast rise-time transients.

To avoid dc latchup after the SCR has fired, the current must be less than the holding current, I_H. To prevent this from happening, the line feed current must be limited to the following conditions:

$$\frac{V_{TP} - V_{RP}}{R_{line} + 2R_{p}} < I_{H}$$

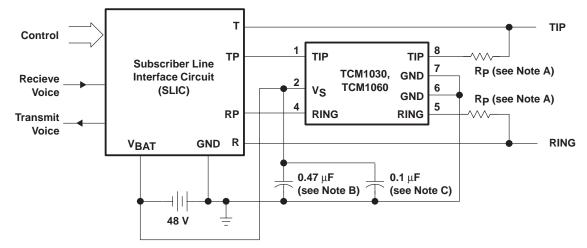
where V_{TP} and V_{RP} are the voltages on TIP and RING, respectively, of the TCM1030 or TCM1060. Induced ac currents into TIP or RING (e.g., power-line inductive coupling) must be less than the trip current to prevent the SCR from firing.



SCTS040A - JUNE 1989 - REVISED MAY 1996

APPLICATION INFORMATION

Line short-circuits to external power sources can damage the suppressor due to excessive power dissipation. Conventional protection techniques, such as fuses or PTC (positive temperature coefficient) thermistors, should be used to eliminate or reduce the fault current.



- NOTES: A. Rp is 100 Ω minimum for TCM1030 and 50 Ω minimum for TCM1060.
 - B. 0.47 µF, 100 V stacked film metalized plastic capacitor
 - C. 0.1 $\mu\text{F},\,100$ V ceramic capacitor

Figure 2. Typical Line-Card Application Circuit



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated